







SN74LV1T00

SCLS737E - SEPTEMBER 2013 - REVISED JULY 2024

SN74LV1T00 Single Power Supply 2-Input Positive NAND Gate CMOS Logic Level Shifter

1 Features

- Single-supply voltage translator at 5.0/3.3/2.5/1.8V
- Operating range of 1.8V to 5.5V
 - Up translation:
 - 1.2V¹ to 1.8V
 - 1.5V¹ to 2.5V
 - 1.8V¹ to 3.3V
 - 3.3V¹ to 5.0V
 - Down translation:
 - 5.0V, 3.3V, 2.5V to 1.8V
 - 5.0V, 3.3V to 2.5V
 - 5.0V to 3.3V
- Logic output is referenced to V_{CC}
- Output drive
 - 8mA output drive at 5V
 - 7mA output drive at 3.3V
 - 3mA output drive at 1.8V
- Characterized up to 50MHz at 3.3V V_{CC}
- 5V tolerance on input pins
- -40°C to 125°C operating temperature range
- Pb-free packages available: SC-70 (DCK)
 - $-2 \times 2.1 \times 0.65$ mm
- Latch-up performance exceeds 250mA order number package body size per JESD 17
- Supports standard Logic pinouts
- CMOS output B compatible with AUP1G and LVC1G families
- 1. Refer to the V_{IH}/V_{II} and output drive for lower V_{CC} condition.

2 Applications

- Industrial controllers
- Telecom
- Portable applications
- Servers
- PC and notebooks
- Automotive

3 Description

SN74LV1T00 is a low voltage CMOS gate logic that operates at a wider voltage range for industrial, portable, telecom, and automotive applications. The output level is referenced to the supply voltage and is able to support 1.8V/2.5V/3.3V/5V CMOS levels

The input is designed with a lower threshold circuit to match 1.8V input logic at VCC = 3.3V and can be used in 1.8V to 3.3V level up translation. In addition, the 5V tolerant input pins enable down translation (e.g. 3.3V to 2.5V output at VCC = 2.5V). The wide VCC range of 1.8V to 5.5V allows generation of desired output levels to connect to controllers or processors.

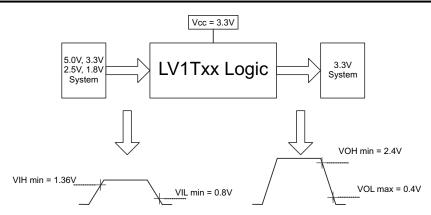
The SN74LV1T00 is designed with current-drive capability of 8 mA to reduce line reflections, overshoot, and undershoot caused by high-drive outputs.

Package Information

| DEVICE NUMBER | PACKAGE ⁽¹⁾ | PACKAGE SIZE(2) | BODY SIZE(3) | | | | | | | |
|------------------|------------------------|-----------------|---------------|--|--|--|--|--|--|--|
| SN74LV1T00 | DBV (SOT-23, 5) | 2.9mm x 2.8mm | 2.9mm x 1.6mm | | | | | | | |
| 31174271100 | DCK (SC-70, 5) | 2mm x 2.1mm | 2mm x 1.25mm | | | | | | | |

- For more information, see Section 12.
- The package size (length × width) is a nominal value and (2) includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.





Switching Thresholds for 1.8V to 3.3V Translation



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4 Related Products

| DEVICE | PACKAGE | DESCRIPTION |
|-------------|----------|--|
| SN74LV1T00 | DCK, DBV | 2-Input Positive-NAND Gate |
| SN74LV1T02 | DCK, DBV | 2-Input Positive-NOR Gate |
| SN74LV1T04 | DCK, DBV | Inverter Gate |
| SN74LV1T08 | DCK, DBV | 2-Input Positive-AND Gate |
| SN74LV1T17 | DCK, DBV | Single Schmitt-Trigger Buffer Gate |
| SN74LV1T14 | DCK, DBV | Single Schmitt-Trigger Inverter Gate |
| SN74LV1T32 | DCK, DBV | 2-Input Positive-OR Gate |
| SN74LV1T34 | DCK, DBV | Single Buffer Gate |
| SN74LV1T86 | DCK, DBV | Single 2-Input Exclusive-Or Gate |
| SN74LV1T125 | DCK, DBV | Single Buffer Gate with 3-state Output |
| SN74LV1T126 | DCK, DBV | Single Buffer Gate with 3-state Output |
| SN74LV4T125 | RGY, PW | Quadruple Bus Buffer Gate With 3-State Outputs |



5 Pin Configuration and Functions

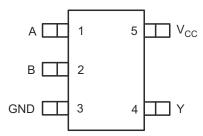


Figure 5-1. DCK or DBV Package, 5-Pin SC70 or SOT-23 (Top View)

Table 5-1. Pin Functions

| Р | IN | TYPE ⁽¹⁾ | DESCRIPTION | | | | | |
|-----------------|-----|---------------------|-----------------|--|--|--|--|--|
| NAME | NO. | ITPE\' | DESCRIPTION | | | | | |
| A | 1 | I | Input A | | | | | |
| В | 2 | I | Input B | | | | | |
| GND | 3 | G | Ground | | | | | |
| Υ | 4 | 0 | Output Y | | | | | |
| V _{CC} | 5 | Р | Positive supply | | | | | |

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

| | | | MIN | MAX | UNIT |
|------------------|------------------------------------|---|------|-----------------------|------|
| V _{CC} | Supply voltage range | | -0.5 | 7.0 | V |
| VI | Input voltage range ⁽²⁾ | | -0.5 | 7.0 | V |
| V | Voltage range applied to a | ny output in the high-impedance or power-off state ⁽²⁾ | -0.5 | 4.6 | V |
| Vo | Voltage range applied to a | ny output in the high or low state ⁽²⁾ | -0.5 | V _{CC} + 0.5 | V |
| I _{IK} | Input clamp current | V ₁ < 0 | | -20 | mA |
| I _{OK} | Output clamp current | $V_O < 0$ or $V_O > V_{CC}$ | | ±20 | mA |
| Io | Continuous output current | | | ±25 | mA |
| | Continuous current through | n V _{CC} or GND | | ±50 | mA |
| TJ | Junction temperature | | | 150 | °C |
| T _{stg} | Storage temperature | | -65 | 150 | °C |

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| | | Human-body model (HBM), per ANSI/ESDA/ JEDEC JS-001 ⁽¹⁾ | ±2000 | |
| V _(ESD) | Electrostatic discharge | Machine Model (MM), per JEDEC specification | ±200 | V |
| | | Charged-device model (CDM), per ANSI/ESDA/ JEDEC JS-002 ⁽²⁾ | ±1000 | |

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted) (1)

| | | | MIN | MAX | UNIT |
|-----------------|---------------------------------------|----------------------------------|-----|-----------------|------|
| V _{CC} | Supply voltage | | 1.6 | 5.5 | V |
| VI | Input voltage | | 0 | 5.5 | V |
| Vo | Output voltage | | 0 | V _{CC} | V |
| | | V _{CC} = 1.8 V | | -3 | |
| | High lovel output ourrent | V _{CC} = 2.5 V | | -5 | mA |
| I _{OH} | nigii-level output current | V _{CC} = 3.3 V | | -7 | ША |
| | High-level output current | V _{CC} = 5.0 V | | -8 | |
| | | V _{CC} = 1.8 V | | 3 | |
| | Low-level output current | V _{CC} = 2.5 V | | 5 | mA |
| I _{OL} | Low-level output current | V _{CC} = 3.3 V | | 7 | ША |
| | | V _{CC} = 5.0 V | | 8 | |
| | | V _{CC} = 1.8 V | | 20 | |
| Δt/Δν | Δv Input transition rise or fall rate | V _{CC} = 3.3 V or 2.5 V | | 20 | ns/V |
| | | V _{CC} = 5.0 V | | 20 | |

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The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



over operating free-air temperature range (unless otherwise noted) (1)

| | | MIN | MAX | UNIT |
|----------------|--------------------------------|-----|-----|------|
| T _A | Operating free-air temperature | -40 | 125 | °C |

¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

6.4 Thermal Information

| | THEDMAL METDIC(1) | DBV | DCK | UNIT |
|-----------------|--|--------|--------|------|
| | THERMAL METRIC ⁽¹⁾ | 5 PINS | 5 PINS | ONII |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 278 | 289.2 | °C/W |

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | V | T _A = | = 25°C | | $T_A = -40^{\circ}C$ to | 125°C | UNIT |
|-----------------|----------------------------|---|---------------------------------------|-----------------------|--------|------|-------------------------|-------|------|
| | PARAMETER | TEST CONDITIONS | V _{cc} | MIN | TYP | MAX | MIN | MAX | UNII |
| | | | V _{CC} = 1.65 V to 1.8 V | 0.94 | | | 1.0 | | |
| | | | V _{CC} = 2.0 V | 1.02 | | | 1.03 | | |
| | | | V _{CC} = 2.25 V to 2.5 V | 1.135 | | | 1.18 | | |
| ., | High-level input | | V _{CC} = 2.75 V | 1.21 | | | 1.23 | | V |
| V _{IH} | voltage | | V _{CC} = 3 V to 3.3 V | 1.35 | | | 1.37 | | V |
| | | | V _{CC} = 3.6 V | 1.47 | | | 1.48 | | |
| | | | V _{CC} = 4.5 V to 5.0 V 2.02 | 2.03 | | | | | |
| | | | V _{CC} = 5.5 V | 2.1 | | | 2.11 | | |
| | | | V _{CC} = 1.65 V to 2.0 V | | | 0.58 | | 0.55 | |
| , | Low-level input | | V _{CC} = 2.25 V to 2.75 V | | | 0.75 | | 0.71 | V |
| / _{IL} | voltage | | V _{CC} = 3 V to 3.6 V | | | 0.8 | | 0.65 | V |
| | | | V _{CC} = 4.5 V to 5.5 V | | | 0.8 | | 0.8 | |
| | | I _{OH} = -20 μA | 1.65 V to 5.5 V | V _{CC} - 0.1 | | | V _{CC} - 0.1 | | |
| | | | 1.65 V | 1.28 | | | 1.21 | | |
| | $I_{OH} = -2.0 \text{ mA}$ | 1.8 V | 1.5 | | | 1.45 | | | |
| | | I _{OH} = -2.3 mA | 0.01/ | 2 | | | 2 | | |
| | | I _{OH} = -3 mA | 2.3 V | 2 | | | 1.93 | | |
| , | | I _{OH} = -3 mA | 2.5 V | 2.25 | | | 2.15 | | ., |
| / _{OH} | | I _{OH} = -3.0 mA | 0.01/ | 2.78 | | | 2.7 | | V |
| | | I _{OH} = -5.5 mA | 3.0 V | 2.6 | | | 2.49 | | |
| | | I _{OH} = -5.5 mA | 3.3 V | 2.9 | | | 2.8 | | |
| | | I _{OH} = -4 mA | 4.5.4 | 4.2 | | | 4.1 | | |
| | | I _{OH} = -8 mA | 4.5 V | 4.1 | | | 3.95 | | |
| | | I _{OH} = -8 mA | 5.0 V | 4.6 | | | 4.5 | | |
| | | I _{OL} = 20 μA | 1.65 V to 5.5 V | | | 0.1 | | 0.1 | |
| | | I _{OL} = 1.9 mA | 1.65 V | | | 0.2 | | 0.25 | |
| | | I _{OH} = 2.3 mA | 0.01/ | | | 0.1 | | 0.15 | |
| , | | I _{OH} = 3 mA | 2.3 V | | | 0.15 | | 0.2 | ., |
| / _{OL} | | I _{OL} = 3 mA | 0.01/ | | | 0.1 | | 0.15 | V |
| | | I _{OL} = 5.5 mA | 3.0 V | | | 0.2 | | 0.252 | |
| | | I _{OL} = 4 mA | 4 | | | 0.15 | | 0.2 | |
| | | I _{OL} = 8 mA | 4.5 V | | | 0.3 | | 0.35 | |
| | A input | V _I = 0 V or V _{CC} | 0 V, 1.8 V, 2.5 V, 3.3 V, 5.5 V | | | 0.12 | | ±1 | μΑ |

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over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | V | T _A | = 25°C | | T _A = -40°C to | UNIT | |
|------------------|--|---------------------------------|----------------|--------|------|---------------------------|------|------|
| PARAMETER | TEST CONDITIONS | TEST CONDITIONS V _{CC} | | | MAX | MIN | MAX | UNII |
| | | 5.0 V | | | 1 | | 10 | |
| | $V_I = 0 \text{ V or } V_{CC}$ | 3.3 V | | | 1 | | 10 | |
| Icc | I _O = 0; open on loading | 2.5 V | | | 1 | | μA | |
| | | 1.8 V | 1 | | | | | |
| Al | One input at 0.3 V or 3.4 V, Other inputs at 0 or V _{CC} , I _O = 0 | 5.5 V | | | 1.35 | | 1.5 | |
| Δl _{CC} | One input at 0.3 V or 1.1 V Other inputs at 0 or V _{CC} , I _O = 0 | | 10 | | 10 | μА | | |
| C _i | V _I = V _{CC} or GND | 3.3 V | | 2 | 10 | 2 | 10 | pF |
| C _o | V _O = V _{CC} or GND | 3.3 V | | 2.5 | | 2.5 | | pF |

6.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Parameter Measurement Information)

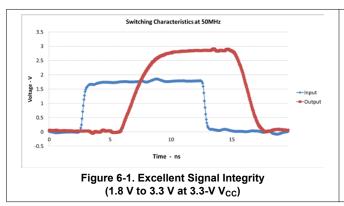
| PARAMETER | FROM | то | FREQUENCY | V _{cc} C _L | T, | _A = 25° | С | T _A = -6 | 5°C to | 125°C | UNIT | | | | | | | | | | | | | |
|-----------------|----------|----------|---------------------------|--------------------------------|----------------|--------------------|--------------|---------------------|----------------|----------------|--------------|--------------|--------------|--------------|--------------|-------|-------|----|-----|-----|--|---|-----|----|
| FARAWETER | (INPUT) | (OUTPUT) | (TYP) | ▼CC | O _L | MIN | TYP | MAX | MIN | TYP | MAX | ONIT | | | | | | | | | | | | |
| | | | | 5.0 V | 15 pF | | 4 | 5 | | 4 | 5 | ns | | | | | | | | | | | | |
| | | | DC to 50 MHz | 3.0 V | 30 pF | | 5.5 | 7.0 | | 5.5 | 7.0 | 115 | | | | | | | | | | | | |
| | | | DC 10 30 WH 12 | DO 10 30 WII 12 | DO 10 30 WH 12 | DO 10 30 WH 12 | | DO 10 30 WI 12 | DO 10 30 WI 12 | DO 10 30 WI 12 | | 3.3 V | 15 pF | | 4.8 | 5 | | 5 | 5.5 | ns | | | | |
| + | Any In | Y | | | 3.5 V | 30 pF | | 5 | 5.5 | | 5.5 | 6.5 | 115 | | | | | | | | | | | |
| t _{pd} | Ally III | ı | DC to 25 MHz DC to 15 MHz | DC to 25 MHz | DC to 25 MHz | DC to 25 MHz | DC to 25 MHz | DC to 25 MHz | DC to 25 MHz | DC to 25 MHz | DC to 25 MHz | DC to 25 MHz | DC to 25 MHz | DC to 25 MHz | DC to 25 MHz | 2.5 V | 15 pF | | 6 | 6.5 | | 7 | 7.5 | no |
| | | | | | | | | | | 2.5 V | 30 pF | | 6.5 | 7.5 | | 7.5 | 8.5 | ns | | | | | | |
| | | | | 1.8 V | 15 pF | | 10.5 | 11 | | 11 | 12 | ns | | | | | | | | | | | | |
| | | | | DC to 15 MHZ | 1.0 V | 30 pF | | 12 | 13 | | 12 | 14 | 115 | | | | | | | | | | | |

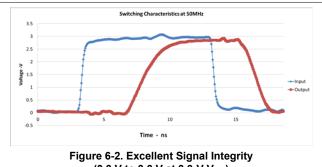
6.7 Operating Characteristics

 $T_A = 25^{\circ}C$

| | PARAMETER | TEST CONDITIONS | V _{cc} | TYP | UNIT |
|----------|-------------------------------|----------------------|--------------------------------|-----|------|
| | | 1.8 V | 1.8 V ± 0.15 V | 10 | |
| | Dower dissination consistence | f = 1 MHz and 10 MHz | 2.5 V ± 0.2 V 3.3 V ± 0.3 V | 10 | |
| C_{pd} | Power dissipation capacitance | I – I MHZ and 10 MHZ | | 10 | pF |
| | | | 5.5 V ± 0.5 V | 10 | |

6.8 Typical Characteristics

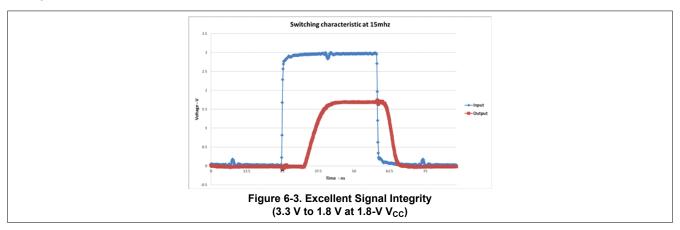




(3.3 V to 3.3 V at 3.3-V V_{CC})

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6.8 Typical Characteristics (continued)



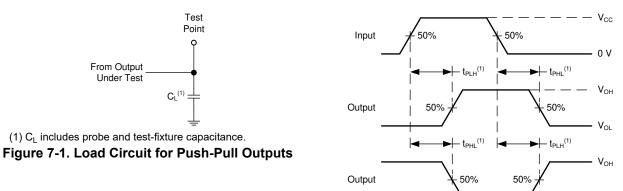


7 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$.

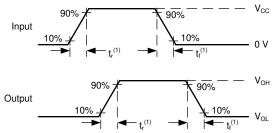
For clock inputs, f_{max} is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



(1) The greater between t_{PLH} and t_{PHL} is the same as $t_{\text{pd}}.$

Figure 7-2. Voltage Waveforms Propagation Delays



(1) The greater between t_r and t_f is the same as t_t.

Figure 7-3. Voltage Waveforms, Input and Output Transition Times

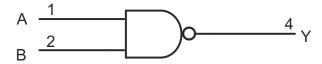
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8 Detailed Description

8.1 Overview

The SN74LV1T00 contains one independent dual input NAND gate with extended voltage operation to allow for level translation. Each gate performs the Boolean function $Y = \overline{A \bullet B}$ in positive logic. The output level is referenced to the supply voltage (V_{CC}) and supports 1.8-V, 2.5-V, 3.3-V, and 5-V CMOS levels.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Clamp Diode Structure

As Figure 8-1 shows, the outputs to this device have both positive and negative clamping diodes, and the inputs to this device have negative clamping diodes only.

CAUTION

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

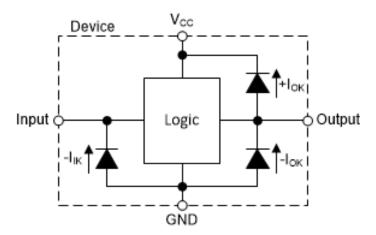


Figure 8-1. Electrical Placement of Clamping Diodes for Each Input and Output

8.3.2 Balanced CMOS Push-Pull Outputs

This device includes balanced CMOS push-pull outputs. The term *balanced* indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads, so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important to limit the output power of the device to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

Unused push-pull CMOS outputs must be left disconnected.

8.3.3 LVxT Enhanced Input Voltage

The SN74LV1T00 belongs to Tl's LVxT family of logic devices with integrated voltage level translation. This family of devices was designed with reduced input voltage thresholds to support up-translation, and inputs tolerant of signals with up to 5.5V levels to support down-translation. For proper functionality, input signals must remain at or above the specified $V_{IL(MAX)}$ for



a LOW input state. Figure 8-2 shows the typical V_{IH} and V_{IL} levels for the LVxT family of devices, as well as the voltage levels for standard CMOS devices for comparison.

The inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using Ohm's law $(R = V \div I)$.

Input signals must transition between valid logic states quickly, as defined by the input transition rate in the *Recommended Operating Conditions* table. Failing to meet this specification will result in excessive power consumption and could cause oscillations. More details can be found in the *Implications of Slow or Floating CMOS Inputs* application report.

Do not leave inputs floating at any time during operation. Unused inputs must be terminated at a valid high or low voltage level. If a system will not be actively driving an input at all times, then a pull-up or pull-down resistor can be added to provide a valid input voltage during these times. The resistor value will depend on multiple factors; however, a $10k\Omega$ resistor is recommended and will typically meet all requirements.

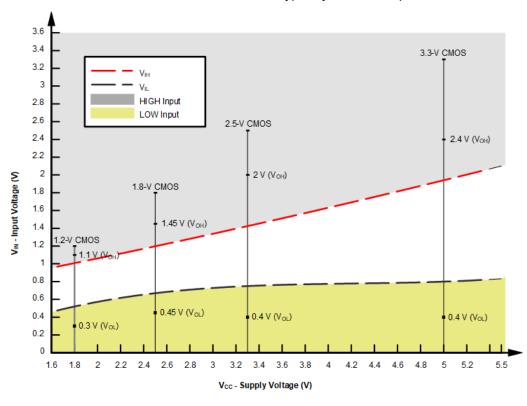


Figure 8-2. LVxT Input Voltage Levels

8.3.3.1 Down Translation

Signals can be translated down using the SN74LV1T00. The voltage applied at the V_{CC} will determine the output voltage and the input thresholds as described in the *Recommended Operating Conditions* and *Electrical Characteristics* tables.

When connected to a high-impedance input, the output voltage will be approximately V_{CC} in the HIGH state, and 0V in the LOW state. Ensure that the input signals in the HIGH state are between $V_{IH(MIN)}$ and 5.5V, and input signals in the LOW state are lower than $V_{IL(MAX)}$ as shown in Figure 8-2.

For example, standard CMOS inputs for devices operating at 5.0V, 3.3V or 2.5V can be down-translated to match 1.8V CMOS signals when operating from 1.8V V_{CC} . See Figure 8-3.

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Down Translation Combinations are as follows:

- 1.8V V_{CC} Inputs from 2.5V, 3.3V, and 5.0V
- 2.5V V_{CC} Inputs from 3.3V and 5.0V
 3.3V V_{CC} Inputs from 5.0V

8.3.3.2 Up Translation

Input signals can be up translated using the SN74LV1T00. The voltage applied at V_{CC} will determine the output voltage and the input thresholds as described in the Recommended Operating Conditions and Electrical Characteristics tables. When connected to a high-impedance input, the output voltage will be approximately V_{CC} in the HIGH state, and 0V in the LOW state.

The inputs have reduced thresholds that allow for input HIGH state levels, which are much lower than standard values. For example, standard CMOS inputs for a device operating at a 5V supply will have a V_{IH(MIN)} of 3.5V. For the SN74LV1T00, V_{IH(MIN)} with a 5V supply is only 2V, which would allow for up-translation from a typical 2.5V to 5V signals.

Ensure that the input signals in the HIGH state are above V_{IH(MIN)} and input signals in the LOW state are lower than $V_{IL(MAX)}$ as shown in Figure 8-3.

Up Translation Combinations are as follows:

- 1.8V V_{CC} Inputs from 1.2V
- 2.5V V_{CC} Inputs from 1.8V
- $3.3 V~V_{CC}$ Inputs from 1.8V and 2.5V $5.0 V~V_{CC}$ Inputs from 2.5V and 3.3V

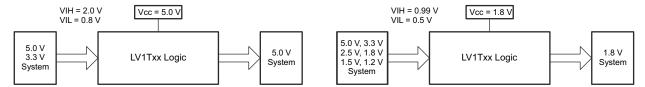


Figure 8-3. LVxT Up and Down Translation Example

8.4 Device Functional Modes

Function Table lists the functional modes of the SN74LV1T00.

Table 8-1. Function Table

| | ITS ⁽¹⁾ evel Input) | OUTPUT (V _{CC} CMOS) ⁽²⁾ | | | | | | | | |
|-----------------------|-----------------------------------|---|--|--|--|--|--|--|--|--|
| Α | В | Y | | | | | | | | |
| Н | Н | L | | | | | | | | |
| L | X | Н | | | | | | | | |
| X | L | Н | | | | | | | | |
| | SUPPLY V _{CC} = | 3.3V | | | | | | | | |
| Α | В | Υ | | | | | | | | |
| V _{IH} (min) | =1.35 V | V _{OH} (min) = 2.9 V | | | | | | | | |
| V _{IL} (max | () =0.8 V | V _{OL} (max)= 0.2 V | | | | | | | | |

- H = High Voltage Level, L = Low Voltage Level, X = Do not Care, Z = High Impedance
- H = Driving High, L = Driving Low, Z = High Impedance State

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9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- μ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in the following layout example.

9.2 Layout

9.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC}, whichever makes more sense for the logic function or is more convenient.

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10 Device and Documentation Support

10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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10.3 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

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10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

11 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

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|------|
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| |
| Page |
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| |
| |

12 Mechanical, Packaging, and Orderable Information

The following packaging information and addendum reflect the most current data available for the designated devices. This data is subject to change without notice and revision of this document.

Product Folder Links: SN74LV1T00

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PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|------------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|-----------------------------------|---------|
| SN74LV1T00DBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 125 | (37VH, 3CEF, NEA3, NEAJ, NEAS) | Samples |
| SN74LV1T00DBVRG4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | NEA3 | Samples |
| SN74LV1T00DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 125 | (WA3, WAJ, WAS) | Samples |
| SN74LV1T00DCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | | WA3 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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OTHER QUALIFIED VERSIONS OF SN74LV1T00:

Automotive : SN74LV1T00-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| SN74LV1T00DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 8.4 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LV1T00DBVR | SOT-23 | DBV | 5 | 3000 | 178.0 | 9.0 | 3.3 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| SN74LV1T00DBVRG4 | SOT-23 | DBV | 5 | 3000 | 178.0 | 9.2 | 3.3 | 3.23 | 1.55 | 4.0 | 8.0 | Q3 |
| SN74LV1T00DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| SN74LV1T00DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.2 | 2.4 | 2.4 | 1.22 | 4.0 | 8.0 | Q3 |
| SN74LV1T00DCKRG4 | SC70 | DCK | 5 | 3000 | 178.0 | 9.2 | 2.4 | 2.4 | 1.22 | 4.0 | 8.0 | Q3 |



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*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74LV1T00DBVR | SOT-23 | DBV | 5 | 3000 | 202.0 | 201.0 | 28.0 |
| SN74LV1T00DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LV1T00DBVRG4 | SOT-23 | DBV | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LV1T00DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LV1T00DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LV1T00DCKRG4 | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.
- 5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side





NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 10. Board assembly site may have different recommendations for stencil design.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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